## NSN 5961-00-057-4801

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View Online at https://aerobasegroup.com/nsn/5961-00-057-4801 **Inclosure Material:** Metal **Overall Length:** 0.260 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.370 inches **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-9 **Electrode Internally-electrically Connected To Case:** Anode **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 160.0 breakdown voltage, collector-to-base, emitter open and 4.0 emitter to base voltage, static, collector open and 140.0 breakdown voltage, collector-to-emitter, base open **Transfer Ratio:** 30.0 static forward current transfer ratio, common-emitter and 120.0 static forward current transfer ratio, common-emitter **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0